

5-V PECL/ECL 1:2 Fanout Buffer

FEATURES

- 1:2 PECL/ECL Fanout Buffer
- Operating Range
 - PECL: $V_{CC} = 4.2\text{ V to }5.7\text{ V}$ With $V_{EE} = 0\text{ V}$
 - NECL: $V_{CC} = 0\text{ V}$ With $V_{EE} = -4.2\text{ V to }-5.7\text{ V}$
- 5-ps Skew Between Outputs
- Support for Clock Frequencies $>2.5\text{ GHz}$
- 265-ps Typical Propagation Delay
- Deterministic Output Value for Open Input Conditions
- Drop-In Compatible With MC10EL11, MC100EL11
- Built-In Input Pulldown Resistors
- Built-In Temperature Compensation

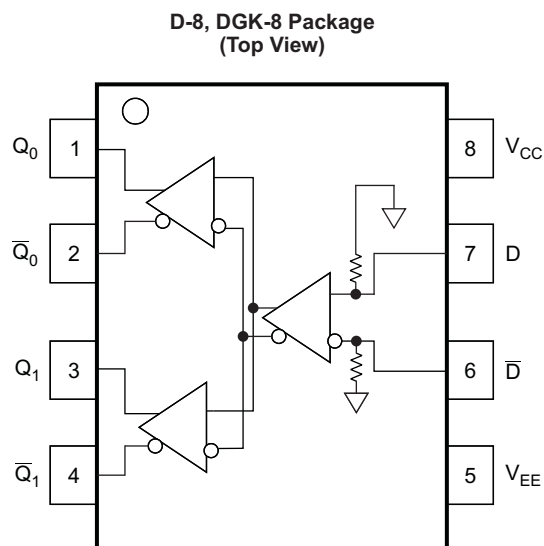
APPLICATIONS

- Data and Clock Transmission Over Backplane
- Signaling Level Conversion

DESCRIPTION

The SN65EL11 is a differential 1:2 PECL/ECL fanout buffer. The device includes circuitry to maintain a known logic level when inputs are in an open condition. The SN65EL11 is housed in an industry-standard SOIC-8 package and is also available in a TSSOP-8 package.

PINOUT ASSIGNMENT



P0065-02

Table 1. Pin Description

PIN	FUNCTION
D, $\bar{D}$	PECL/ECL data inputs
Q_0 , $\bar{Q}_0$, Q_1 , $\bar{Q}_1$	PECL/ECL outputs
V_{CC}	Positive supply
V_{EE}	Negative supply

ORDERING INFORMATION⁽¹⁾

PART NUMBER	PART MARKING	PACKAGE	LEAD FINISH
SN65EL11D	SN65EL11	SOIC	NiPdAu
SN65EL11DGK	SN65EL11	SOIC-TSSOP	NiPdAu

(1) Leaded device options not initially available; contact a sales representative for further details.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

PARAMETER	CONDITIONS	VALUE	UNIT
Absolute PECL-mode supply voltage, V_{CC}	$V_{EE} = 0\text{ V}$	6	V
Absolute NECL-mode supply voltage, V_{EE}	$V_{CC} = 0\text{ V}$	–6	V
PECL-mode input voltage	$V_{EE} = 0\text{ V}; V_I \leq V_{CC}$	6	V
NECL-mode input voltage	$V_{CC} = 0\text{ V}; V_I \geq V_{EE}$	–6	V
Output current	Continuous	50	mA
	Surge	100	mA
Operating temperature range		–40 to 85	°C
Storage temperature range		–65 to 150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

POWER DISSIPATION RATINGS

PACKAGE	CIRCUIT BOARD MODEL	POWER RATING $T_A < 25^\circ\text{C}$ (mW)	THERMAL RESISTANCE, JUNCTION-TO-AMBIENT, NO AIRFLOW	DERATING FACTOR $T_A > 25^\circ\text{C}$ (mW/°C)	POWER RATING $T_A = 85^\circ\text{C}$ (mW)
SOIC	Low-K	719	139	7	288
	High-K	840	119	8	336
SOIC-TSSOP	Low-K	469	213	5	188
	High-K	527	189	5	211

THERMAL CHARACTERISTICS

PARAMETER		PACKAGE	VALUE	UNIT
θ_{JB}	Junction-to-board thermal resistance	SOIC	79	°C/W
		SOIC-TSSOP	120	
θ_{JC}	Junction-to-case thermal resistance	SOIC	98	°C/W
		SOIC-TSSOP	74	

KEY ATTRIBUTES

CHARACTERISTICS	VALUE
Internal input pulldown resistor	75 k Ω
Moisture sensitivity level	Level 1
Flammability rating (oxygen index: 28 to 34)	UL 94 V-0 at 0.125 in
ESD-HBM	4 kV
ESD-machine model	200 V
Meets or exceeds JEDEC Spec EIA/JESD78 latchup test	

PECL DC CHARACTERISTICS⁽¹⁾ ($V_{CC} = 5\text{ V}$; $V_{EE} = 0\text{ V}$)⁽²⁾

PARAMETER	–40°C			25°C			85°C			UNIT
	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
I_{CC} Power-supply current		18	26		21	26		23	26	mA
V_{OH} Output HIGH voltage ⁽³⁾	3915		4120	3915	4000	4120	3915		4120	mV
V_{OL} Output LOW voltage ⁽³⁾	3170		3380	3170	3288	3380	3170		3380	mV
V_{IH} Input HIGH voltage (single-ended)	3835		4120	3835		4120	3835		4120	mV
V_{IL} Input LOW voltage (single-ended)	3190		3525	3190		3525	3190		3525	mV
V_{IHCMR} Input HIGH voltage, common-mode range (differential) ⁽⁴⁾	2.5		4.6	2.5		4.6	2.5		4.6	V
I_{IH} Input HIGH current			150			150			150	μA
I_{IL} Input LOW current	0.5			0.5			0.5			μA

(1) The device meets these specifications after thermal equilibrium has been established when mounted in a test socket or printed-circuit board with maintained transverse airflow greater than 500 lfm (2.54 m/s). Electrical parameters are assured only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

(2) Input and output parameters vary 1:1 with V_{CC} . V_{EE} can vary +0.25 V / –0.5 V.

(3) Outputs are terminated through a 50-Ω resistor to $V_{CC} - 2\text{ V}$.

(4) V_{IHCMR} min varies 1:1 with V_{EE} ; V_{IHCMR} max varies 1:1 with V_{CC} . The V_{IHCMR} range is referenced to the more-positive side of the differential input signal. Normal operation is obtained if the HIGH level falls within the specified range and the peak-to-peak voltage lies between V_{PP} min and 1 V.

NECL DC CHARACTERISTICS⁽¹⁾ ($V_{CC} = 0\text{ V}$; $V_{EE} = 5\text{ V}$)⁽²⁾

PARAMETER	–40°C			25°C			85°C			UNIT
	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
I_{EE} Power-supply current		19	26		21	26		23	26	mA
V_{OH} Output HIGH voltage ⁽³⁾	–1085		–880	–1025	–995	–880	–1025		–880	mV
V_{OL} Output LOW voltage ⁽³⁾	–1830		–1620	–1810	–1712	–1620	–1810		–1620	mV
V_{IH} Input HIGH voltage (single-ended)	–1165		–880	–1165		–880	–1165		–880	mV
V_{IL} Input LOW voltage (single-ended)	–1810		–1475	–1810		–1475	–1810		–1475	mV
V_{IHCMR} Input HIGH voltage, common-mode range (differential) ⁽⁴⁾	–2.5		–0.4	–2.5		–0.4	–2.5		–0.4	V
I_{IH} Input HIGH current			150			150			150	μA
I_{IL} Input LOW current	0.5			0.5			0.5			μA

(1) The device meets these specifications after thermal equilibrium has been established when mounted in a test socket or printed-circuit board with maintained transverse airflow greater than 500 lfm (2.54 m/s). Electrical parameters are assured only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

(2) Input and output parameters vary 1:1 with V_{CC} . V_{EE} can vary +0.25 V / –0.5 V.

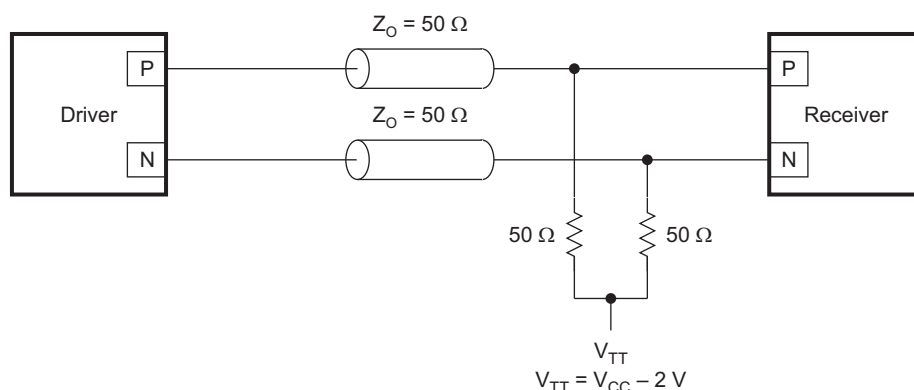
(3) Outputs are terminated through a 50-Ω resistor to $V_{CC} - 2\text{ V}$.

(4) V_{IHCMR} min varies 1:1 with V_{EE} ; V_{IHCMR} max varies 1:1 with V_{CC} . The V_{IHCMR} range is referenced to the more-positive side of the differential input signal. Normal operation is obtained if the HIGH level falls within the specified range and the peak-to-peak voltage lies between V_{PP} min and 1 V.

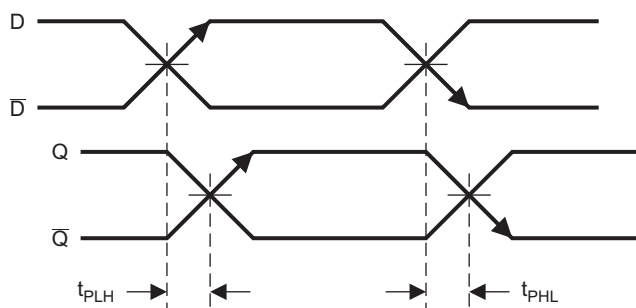
AC CHARACTERISTICS⁽¹⁾ ($V_{CC} = 5\text{ V}$; $V_{EE} = 0\text{ V}$ or $V_{CC} = 0\text{ V}$; $V_{EE} = -5\text{ V}$)⁽²⁾

PARAMETER		−40°C			25°C			85°C			UNIT
		MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
f _{MAX}	Maximum switching frequency ⁽³⁾ (see Figure 6)	3.5			3.4			3.1			GHz
t _{PLH} /t _{PHL}	Propagation delay to output (see Figure 2)	200		300	200		300	200		300	ps
t _{SKEW}	Device skew ⁽⁴⁾ (see Figure 5)	7		15	7		15	7		15	ps
	Duty cycle skew ⁽⁵⁾	5		15	5		15	5		15	
t _{JITTER}	Random clock jitter (RMS)	0.2			0.2			0.2			ps
V _{PP}	Input swing ⁽⁶⁾ (see Figure 3)	150		1000	150		1000	150		1000	mV
t _r /t _f	Q-output rise/fall times (20%–80%) (see Figure 4)	150		250	150		250	150		250	ps

- (1) The device meets these specifications after thermal equilibrium has been established when mounted in a test socket or printed-circuit board with maintained transverse airflow greater than 500 lfpm (2.54 m/s). Electrical parameters are assured only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.
- (2) Input and output parameters vary 1:1 with V_{CC} . V_{EE} can vary +0.25 V / –0.5 V.
- (3) Maximum switching frequency is measured at an output amplitude of 300 mVpp.
- (4) Within-device skew defined as identical transitions on similar paths through a device.
- (5) Duty cycle skew is the difference between a t_{PLH} and t_{PHL} propagation delay through a device.
- (6) $V_{PP(min)}$ is the minimum input swing for which ac parameters are assured.

Typical Termination for Output Driver


S0078-02

Figure 1. Typical Termination for Output Driver


T0400-01

Figure 2. Propagation Delay

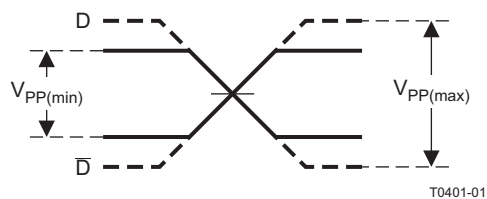


Figure 3. Input Voltage Swing

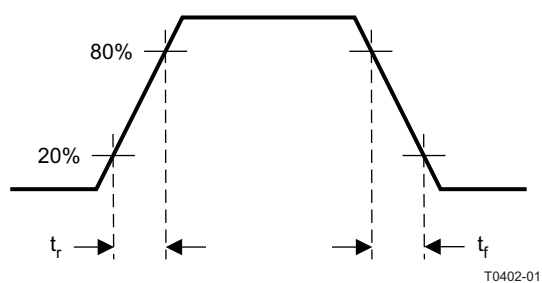
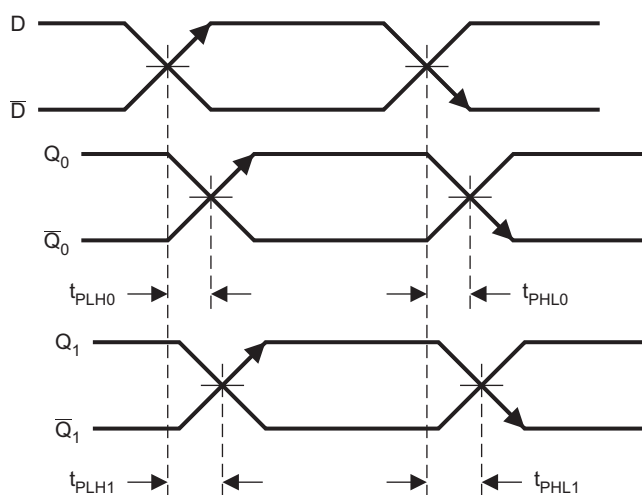


Figure 4. Output Rise and Fall Times



$$\text{Device Skew} = [(t_{PLH1} - t_{PLH0}), (t_{PHL1} - t_{PHL0})]$$

T0403-01

Figure 5. Device Skew

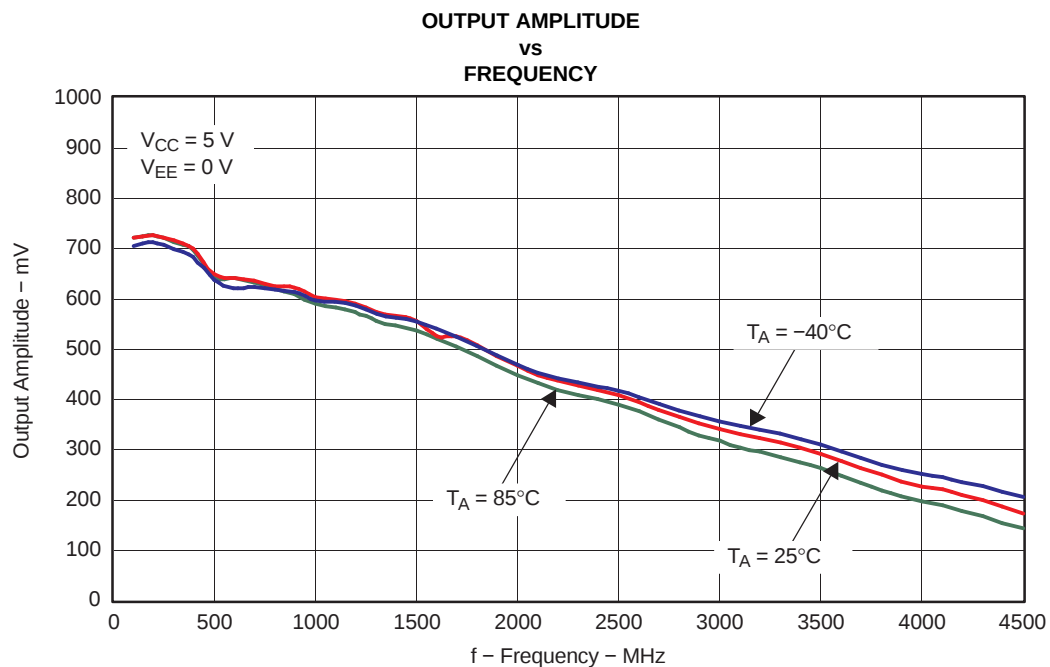


Figure 6.

G001

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN65EL11D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	EL11	Samples
SN65EL11DGK	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	SILI	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

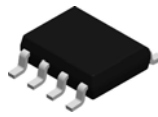
(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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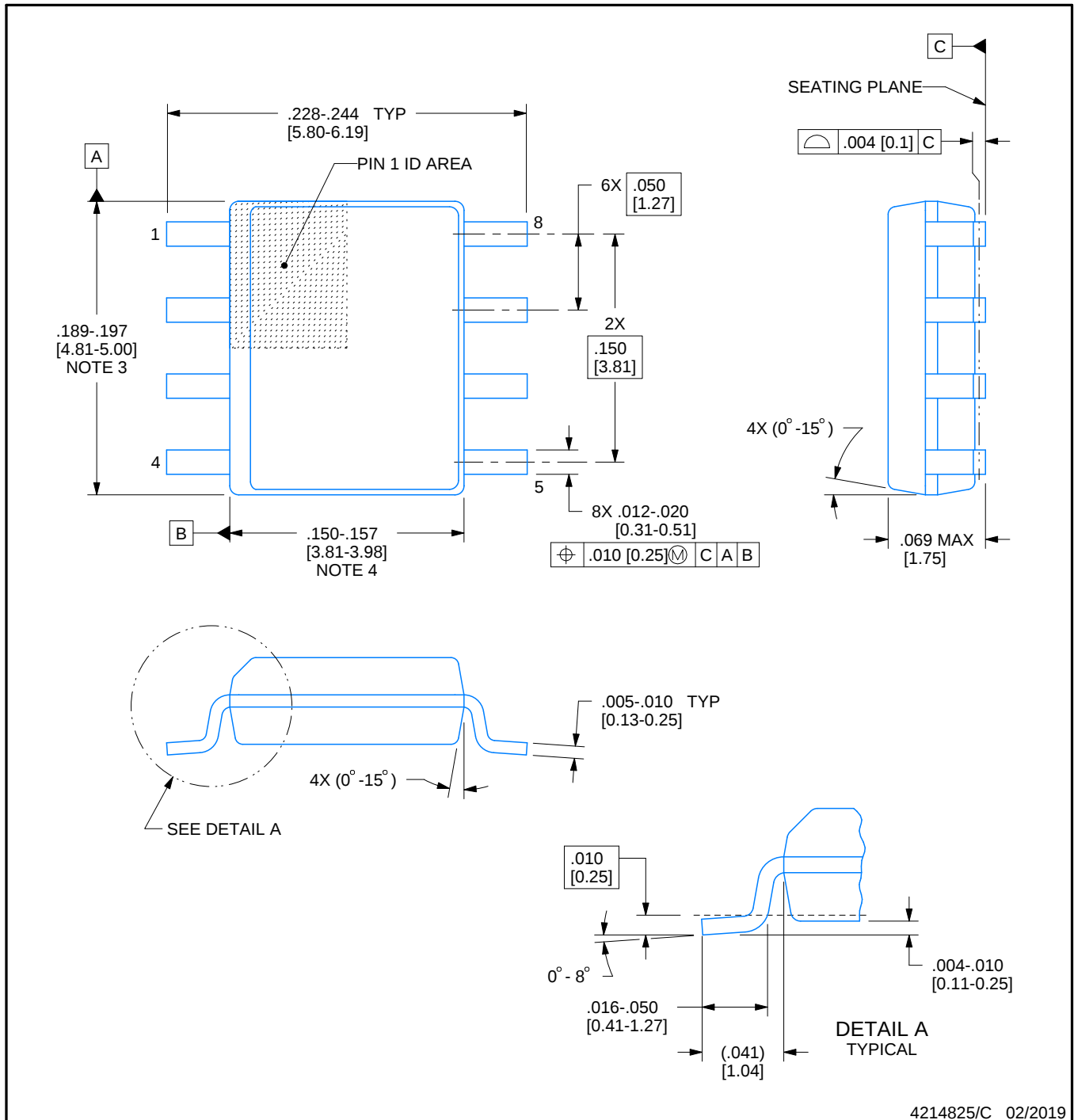


D0008A

PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



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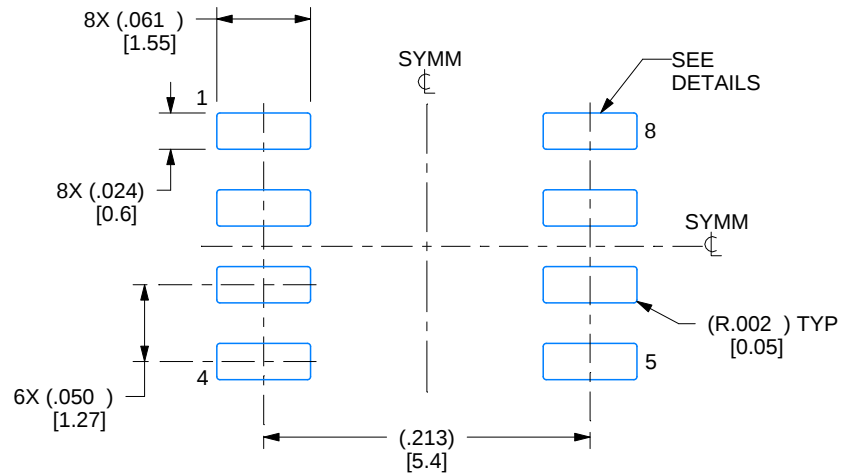
NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

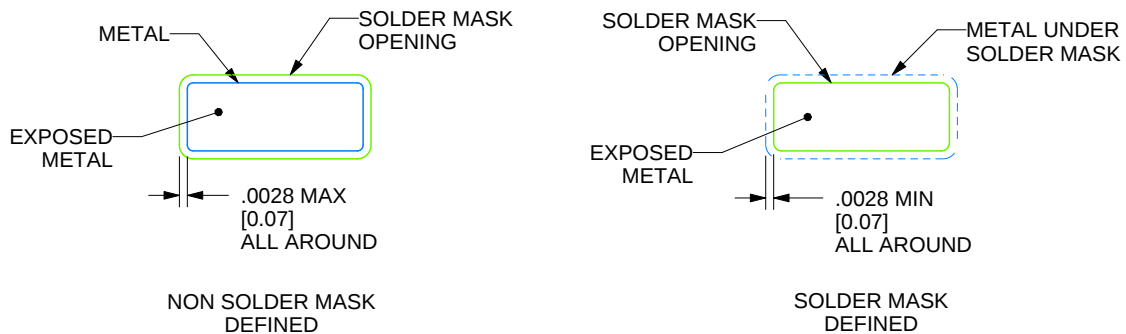
D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

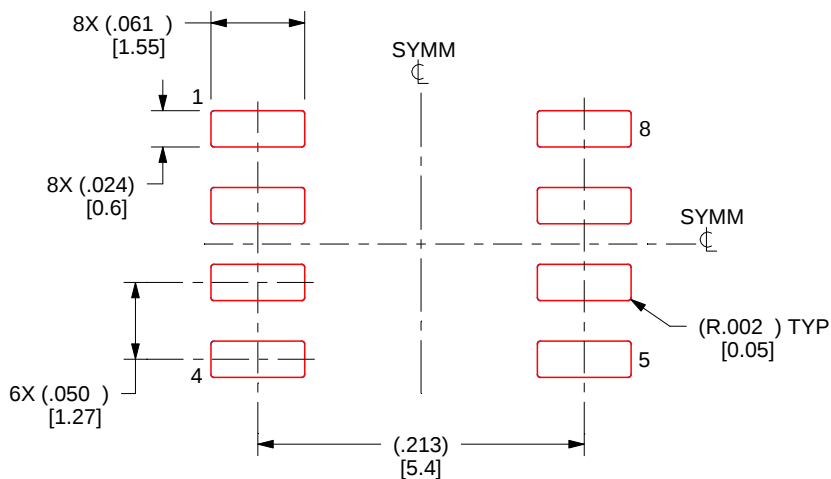
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

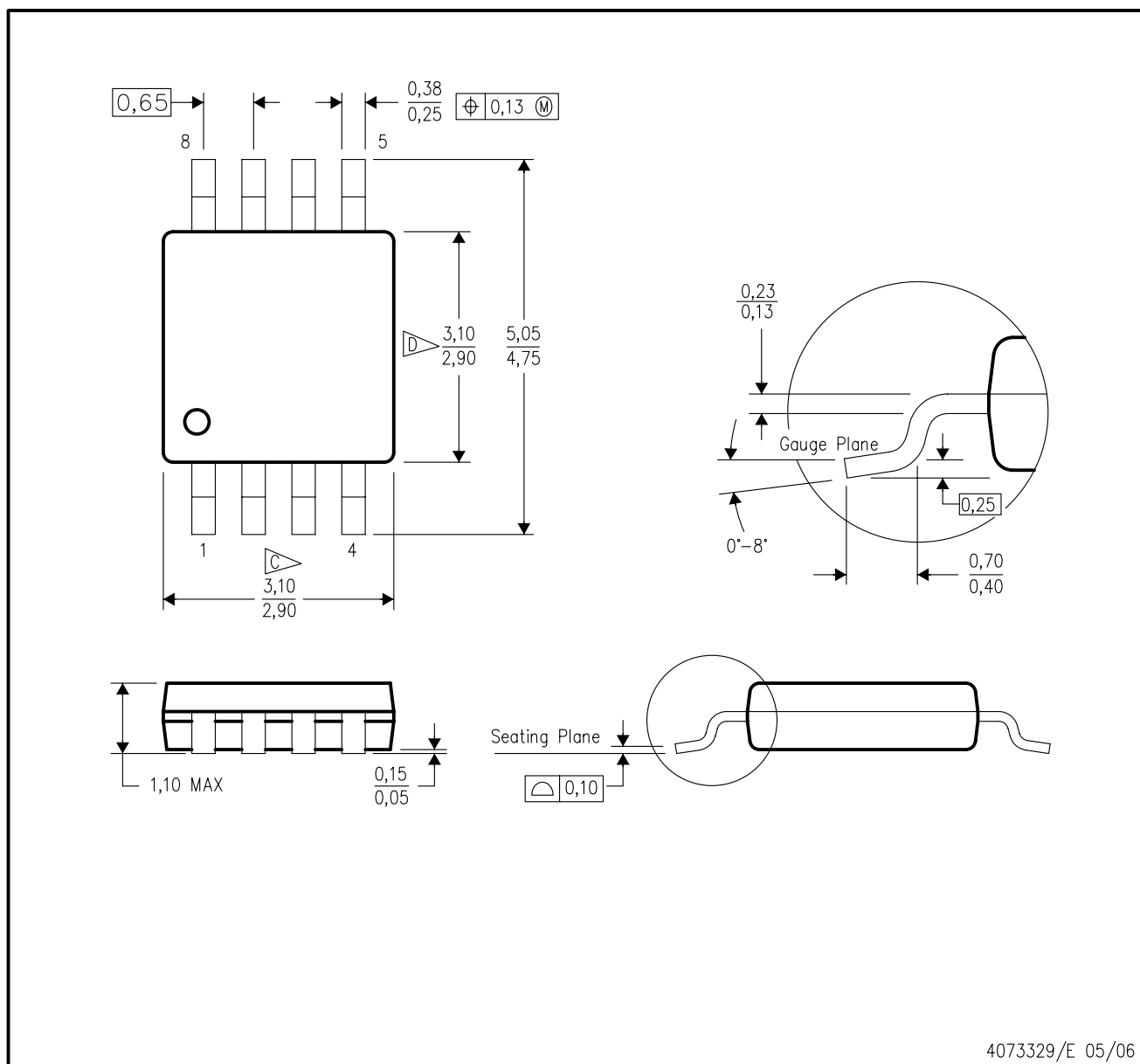
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NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE

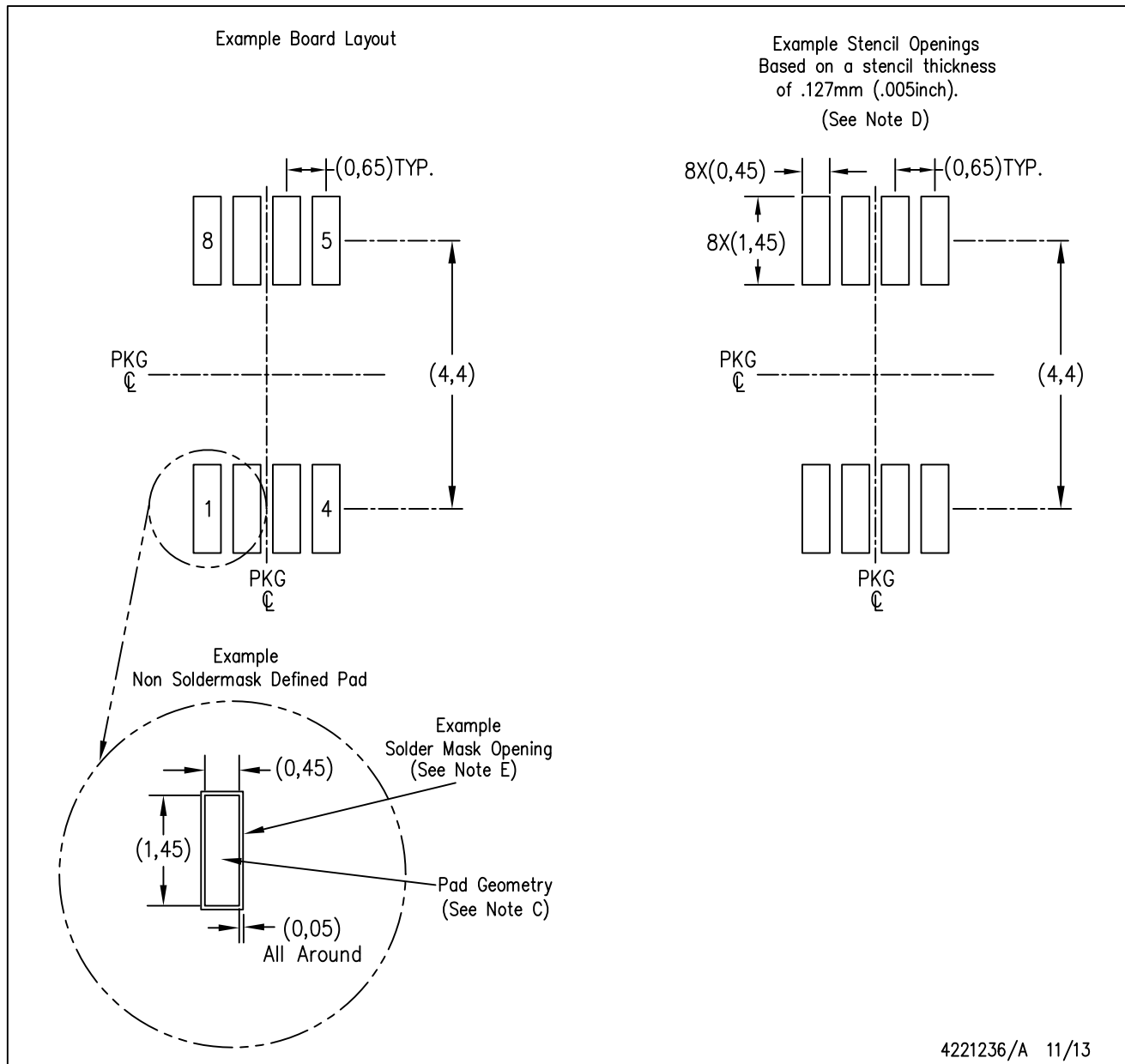


NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
- D. Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.

DGK (S-PDSO-G8)

PLASTIC SMALL OUTLINE PACKAGE



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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